THE DATASHEET OF

3C92C

Hi-Reliability Optically Coupled Isolator

3C91C, 3C92C (TX), 3N243, 3N244, 3N245 (TX), 3N262

Features:

- TO-72 hermetically sealed package
- 1 kVDC electrical isolation
- High current transfer ratio
- TX devices processed to MIL-PRF-19500

Description:

Each device is a high reliability optically coupled isolator that consists of an infrared emitting diode and a NPN silicon phototransistor which are mounted in a hermetically sealed TO-72 package. The **3C91C** and **3C92C** have a 935 nm wavelength, whereas the **3N243**, **3N244**, **3N245** and **3N262** have an 880 nm wavelength. All devices have 0.50" (12.70 mm) leads. Electrical characteristics vary.

TX devices are processed to OPTEK's military screening program patterned after MIL-PRF-19500.

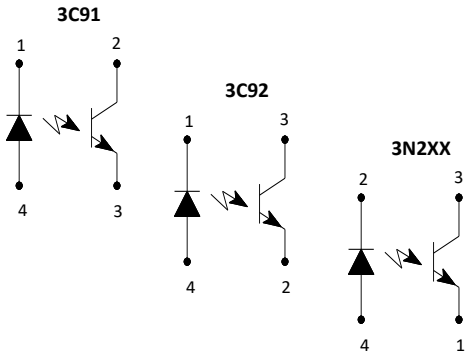
Please refer to Application Bulletins 208 and 210 for additional design information and reliability (degradation) data.

Contact your local representative or OPTEK for more information.

Applications:

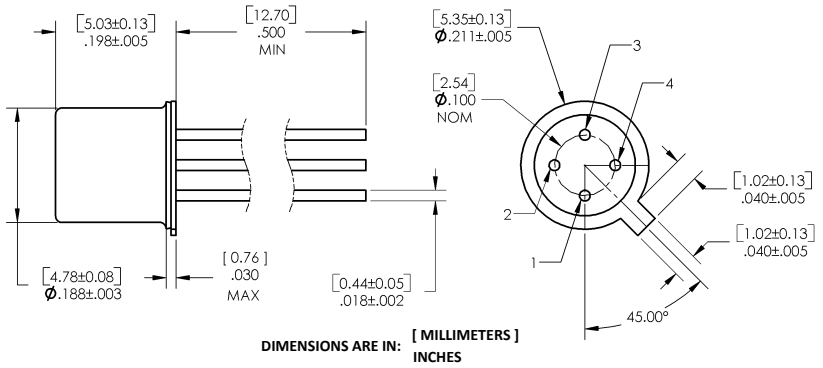
- High-voltage isolation between input and output
- Electrical isolation in dirty environments
- Industrial equipment
- Medical equipment
- Office equipment

Part Number	LED Peak Wavelength	Sensor	Isolation Voltage (,000)	CTR Min / Max	I_F (mA) Typ / Max	V_{CE} (V) Typ / Max	Lead Length
3C91C	935 nm	Transistor	1	0.3 / 2.0	10 / 50	10 / 50	0.50"
3C92C (TX)							
3N243	880 nm			0.15 / NA	3 / 40	10 / 30	
3N244				0.3 / NA			
3N245 (TX)				0.6 / NA			
3N262				1.0 / 5.0	1 / 40	5 / 30	



Pin #	3C91	3C92	3N2XX
1	Cathode	Cathode	Emitter
2	Collector	Emitter	Cathode
3	Emitter	Collector	Collector
4	Anode	Anode	Anode

Phototransistor Collector is connected to the Header-Base-Case for ALL versions



General Note
TT Electronics reserves the right to make changes in product specification without notice or liability. All information is subject to TT Electronics' own data and is considered accurate at time of going to print.

© TT electronics plc

TT Electronics | OPTEK Technology
2900 E. Plano Pkwy, Plano, TX 75074 | Ph: +1 972 323 2200
www.ttelectronics.com | sensors@ttelectronics.com

Electrical Specifications

Absolute Maximum Ratings (T_A = 25° C unless otherwise noted)

Operating Temperature Range	-55° C to +125° C
Storage Temperature Range	-65° C to +150° C
Input to Output Isolation Voltage	± 1 kVDC(1)
Lead Soldering Temperature [1/16 inch (1.6 mm) from case for 5 seconds with soldering iron]	260° C(2)

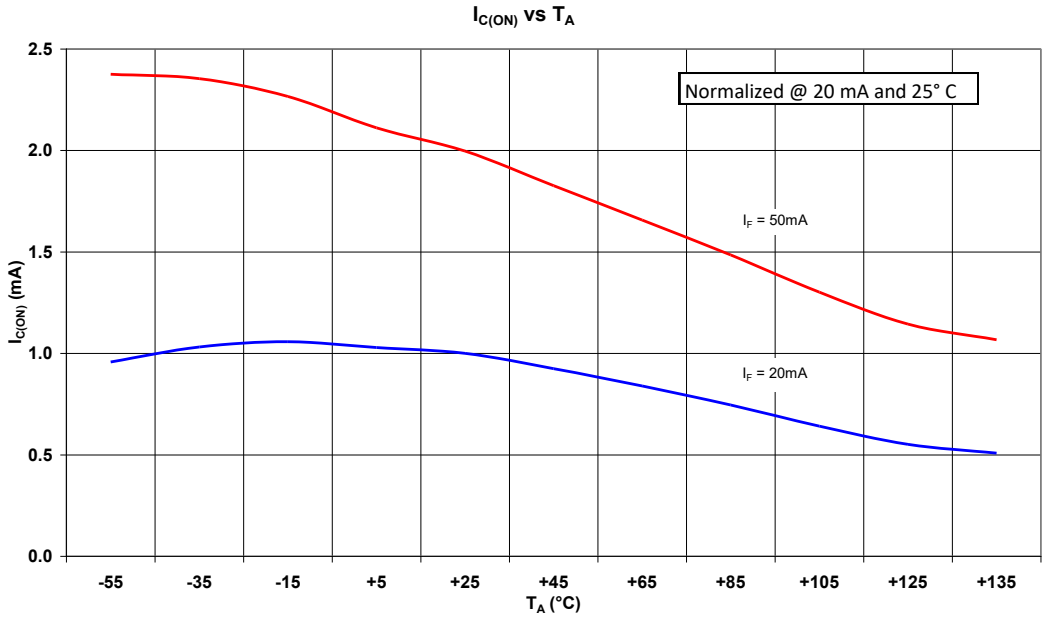
Input Diode

Forward DC Current	40 mA
Reverse Voltage	2.0 V
Power Dissipation	60 mW(3)

Output Phototransistor

Continuous Collector Current	30 mA
Collector-Emitter Voltage	30 V
Emitter-Collector Voltage	5.0 V
Power Dissipation	200 mW(4)

Notes:
1. Measured with input leads shorted together and output leads shorted together.
2. RMA flux is recommended. Duration can be extended to 10 seconds maximum when flow soldering.
3. Derate linearly 2.0 mW/° C above 25° C.
4. Derate linearly 0.60 mW/° C above 65° C.



General Note
TT Electronics reserves the right to make changes in product specification without notice or liability. All information is subject to TT Electronics' own data and is considered accurate at time of going to print.

© TT electronics plc

TT Electronics | OPTEK Technology
2900 E. Plano Pkwy, Plano, TX 75074 | Ph: +1 972 323 2200
www.ttelectronics.com | sensors@ttelectronics.com

Electrical Specifications

Electrical Characteristics (T_A = 25° C unless otherwise noted)

SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS
Input Diode						
V_F	Forward Voltage					
	3C91C, 3C92C (TX)	-	-	1.2		I_F = 2 mA
	3C91C, 3C92C (TX)	-	-	1.5		I_F = 50 mA
	3N243, 3N244, 3N245 (TX)	0.8	-	1.3		I_F = 10 mA
	3N243, 3N244, 3N245 (TX)	1.0	-	1.5	V	I_F = 10 mA, T_A = -55° C
	3N243, 3N244, 3N245 (TX)	0.7	-	1.2		I_F = 10 mA, T_A = -100° C
	3N262	0.8	-	1.5		I_F = 10 mA
	3N262	1.0	-	1.7		I_F = 10 mA, T_A = -55° C
	3N262	0.7	-	1.3		I_F = 10 mA, T_A = -100° C
V_R	Reverse Voltage				V	
	3C91C, 3C92C (TX)	7	-	-		I_R = 0.1 mA
I_R	Reverse Current					
	3C91C, 3C92C (TX)	-	-	1	µA	V_R= 3.0 V
	3N243, 3N244, 3N245 (TX)	-	-	100		V_R= 2.0 V
	3N262	-	-	100		V_R= 2.0 V
C_{IN}	Diode Capacitance				pF	
	3C91C, 3C92C (TX)	-	25	-		V = 0, f = 1 MHz
Output Phototransistor						
$V_{(BR)CEO}$	Collector-Emitter Breakdown Voltage					
	3C91C, 3C92C (TX)	50	-	-		I_C = 10.0 mA
	3N243, 3N244, 3N245 (TX)	30	-	-	V	I_C = 1.0 mA
	3N262	40	-	-		I_C = 1.0 mA
$V_{(BR)ECO}$	Emitter-Collector Breakdown Voltage					
	3C91C, 3C92C (TX)	7	-	-	V	I_C = 10 µA
	3N243, 3N244, 3N245 (TX)	5	-	-		I_E = 100 µA
	3N262	7	-	-		I_E = 100 µA
I_{CEO}	Collector Dark Current					
	3C91C, 3C92C (TX)	-	-	10	nA	V_{CE} = 5 V
	3C91C, 3C92C (TX)	-	-	50	nA	V_{CE} = 50 V
	3N243, 3N244, 3N245 (TX)	-	-	100	nA	V_{CE} = 10.0 V
	3N243, 3N244, 3N245 (TX)	-	-	100	µA	V_{CE} = 10.0 V, T_A = 100° C
	3N262	-	-	100	µA	V_{CE} = 10.0 V
	3N262	-	-	100	µA	V_{CE} = 10.0 V, T_A = 100° C

General Note
TT Electronics reserves the right to make changes in product specification without notice or liability. All information is subject to TT Electronics' own data and is considered accurate at time of going to print.

© TT electronics plc

Electrical Specifications

Electrical Characteristics (T_A = 25° C unless otherwise noted)

SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS
Coupled						
$I_{C(ON)}$	On-State Collector Current				mA	
	3C91C, 3C92C (TX)	4.0	-	-		I_F = 10 mA , V_{CE} = 5 V
	3C91C, 3C92C (TX)	3.0	-	20		I_F = 10 mA , V_{CE} = 0.4 V
	3N243	1.5	-	-		I_F = 10 mA , V_{CE} = 10.0 V
	3N243	0.3	-	-		I_F = 3 mA , V_{CE} = 10.0 V
	3N243	0.5	-	-		I_F = 10 mA , V_{CE} = 10.0 V, T_A = 55° C
	3N243	0.5	-	-		I_F = 10 mA , V_{CE} = 10.0 V, T_A = 100° C
	3N244	3.0	-	-		I_F = 10 mA , V_{CE} = 10.0 V
	3N244	0.8	-	-		I_F = 3 mA , V_{CE} = 10.0 V
	3N244	1.0	-	-		I_F = 10 mA , V_{CE} = 10.0 V, T_A = 55° C
	3N244	1.0	-	-		I_F = 10 mA , V_{CE} = 10.0 V, T_A = 100° C
	3N245 (TX)	6.0	-	-		I_F = 10 mA , V_{CE} = 10.0 V
	3N245 (TX)	1.5	-	-		I_F = 3 mA , V_{CE} = 10.0 V
	3N245 (TX)	1.5	-	-		I_F = 10 mA , V_{CE} = 10.0 V, T_A = 55° C
	3N245 (TX)	1.5	-	-		I_F = 10 mA , V_{CE} = 10.0 V, T_A = 100°
	3N262	1.0	-	5		I_F = 1 mA , V_{CE} = 5.0 V
	3N262	1.4	-	-		I_F = 2.0 mA , V_{CE} = 5.0 V, T_A = 55° C
	3N262	1.0	-	-		I_F = 2.0 mA , V_{CE} = 5.0 V, T_A = 100° C
$V_{CE(SAT)}$	Collector-Emitter Saturation Voltage				V	
	3C91C, 3C92C (TX)	-	-	0.4		I_F = 50 mA , I_C = 10 mA
	3N243, 3N244, 3N245 (TX)	-	-	0.3		I_F = 20 mA , I_C = 1.50 mA
	3N243, 3N244, 3N245 (TX)	-	-	0.3		I_F = 20 mA , I_C = 3.0 mA
	3N243, 3N244, 3N245 (TX)	-	-	0.3		I_F = 20 mA , I_C = 6.0 mA
	3N262	-	-	0.3		I_F = 2.0 mA , I_C = 0.50 mA
	3N262	-	-	0.3		I_F = 2.0 mA , I_C = 1.0 mA
	3N262	-	-	0.3		I_F = 2.0 mA , I_C = 2.0 mA
t_{ON}	Turn-on Time				µs	
	3C91C, 3C92C (TX)	-	-	9		V_{CC} = 5 V, I_C = 2 mA, R_L = 100 Ω
t_{IOFF}	Turn-off Time				µs	
	3C91C, 3C92C (TX)	-	-	6		V_{CC} = 5 V, I_C = 2 mA, R_L = 100 Ω

General Note
TT Electronics reserves the right to make changes in product specification without notice or liability. All information is subject to TT Electronics' own data and is considered accurate at time of going to print.

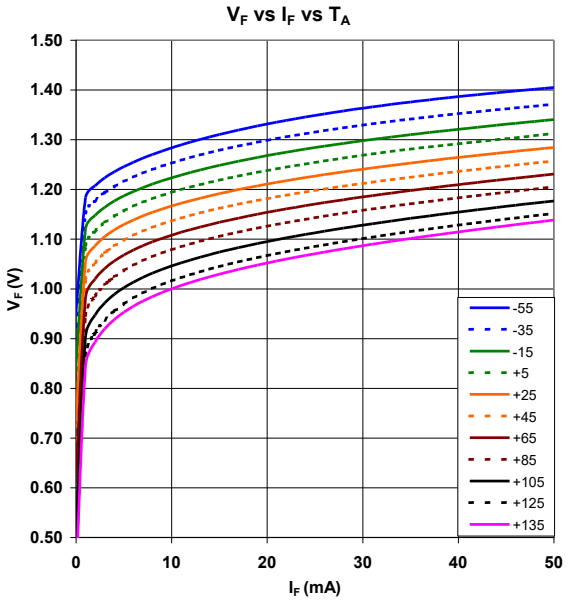
© TT electronics plc

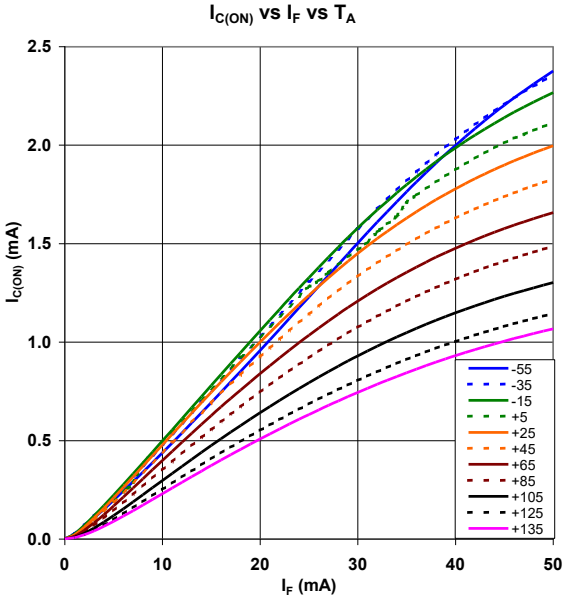
Electrical Specifications

Electrical Characteristics (T_A = 25° C unless otherwise noted)

SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS
Coupled						
C_{IO}	Input-to-Output Capacitance 3C91C, 3C92C (TX) 3N243, 3N244, 3N245 (TX) 3N262	 - - -	 2 - -	 2.5 5.0 5.0	pF	f = 1 MHz V_{IO} = 0 V, f = 1.00 MHz(1) V_{IO} = 0 V, f = 1.00 MHz(1)
I_{IO}	Leakage Input -to-Output 3N243, 3N244, 3N245 (TX) 3N262	 - -	 - -	 100 10	nA	 V_{IO} = ± 1.00 kVDC(1) V_{IO} = ± 1.00 kVDC(1)
R_{IO}	Isolation Resistance 3C91C, 3C92C (TX)	 10^9	 -	 -	Ω	 V_{IO} = +1 kV
t_r	Output Rise Time 3N243, 3N244, 3N245 (TX) 3N262	 - -	 - -	 10 20	µs	 V_{CC} = 10.0 V, I_F = 10.0 mA, R_L = 100 Ω(2) V_{CC} = 10.0 V, I_F = 5.0 mA, R_L = 100 Ω(2)
t_f	Output Fall Time 3N243, 3N244, 3N245 (TX) 3N262	 - -	 - -	 10 10	µs	 V_{CC} = 10.0 V, I_F = 10.0 mA, R_L = 100 Ω(2) V_{CC} = 10.0 V, I_F = 5.0 mA, R_L = 100 Ω(2)

Notes:
1. Measured with input leads shorted together and output leads shorted together.
2. The input waveform is supplied by a generator with the following characteristics: Z_{OUT} = 50 Ω, t_r ≤ 15 ns, duty cycle ~ 1%, pulse width ~ 100 ms.





General Note
TT Electronics reserves the right to make changes in product specification without notice or liability. All information is subject to TT Electronics' own data and is considered accurate at time of going to print.

© TT electronics plc

Looking for pricing, stock, or lifecycle information?

Click below to explore more details on WIN SOURCE:

- View 3C92C on WIN SOURCE
- TT Electronics Information

Optimize Your Supply Chain with WIN SOURCE Solutions

- Global Sourcing Solution
- Obsolete Management
- Cost Control Management
- Shortage Management
- Alternative Solution
- Excess Inventory Management